RIPPLE-CARRY BINARY COUNTER/DIVIDERS:

4020 - 14 STAGE
4024 - 7 STAGE
4040 - 12 STAGE

GENERAL DESCRIPTION

These devices are monolithic I.C's fabricated with standard AL-gate CMOS technology. All counter stages are master-slave flip-flops.
The state of a counter advances one count on the negative transition of each input pulse. A high level on the RESET line resets the counter to its all zeros stage. Schmitt trigger action on the input-pulse line permits unlimited clock rise and fall times. All inputs and outputs are buffered. MMC 4020, MMC 4040 are available in 16-lead dual-in-line ceramic or plastic package and MMC 4024 is available in 14-lead dual-in-line plastic or ceramic package.

FEATURES

- Medium-speed operation
- Fully static operation
- Buffered inputs and outputs
- Common RESET
- Quiescent current specified to 20 V
- Standardized symmetrical output characteristics
- 5 V, 10 V, and 15 V parametric ratings

ABSOLUTE MAXIMUM RATINGS

V_{DD}*	Supply voltage: G and H types	-0.5 to	20	V
	E and F types	-0.5 to	18	V
V_I	Input voltage	-0.5 to	V_{DD}+0.5	V
I_I	DC input current (any one input)		±10	mA
P_{tot}	Total power dissipation (per package)		200	mW
	Dissipation per output transistor for T_A = full package-temperature range		100	mW
T_A	Operating temperature : G and H types	-55 to	125	°C
	E and F types	-40 to	85	°C
T_{stg}	Storage temperature	-65 to	150	°C

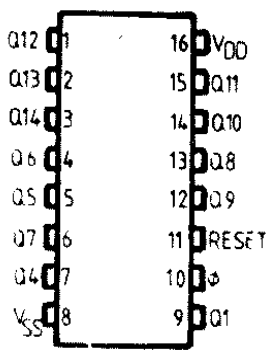
* All voltage values are referred to V_{SS} pin voltage

RECOMMENDED OPERATING CONDITIONS

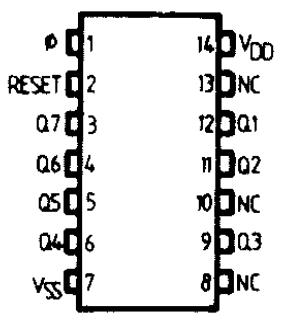
V_{DD}*	Supply voltage: G and H types	3 to	18	V
	E and F types	3 to	15	V
V_I	In put voltage	0 to	V_{DD}	V
T_A	Operating temperature : G and H types	-55 to	125	°C
	E and F types	-40 to	85	°C

CONNECTION DIAGRAM

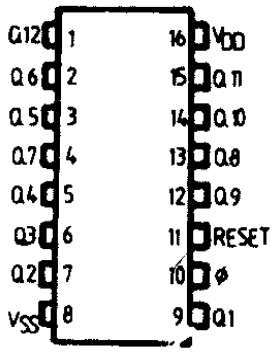
MMC 4020



MMC 4024

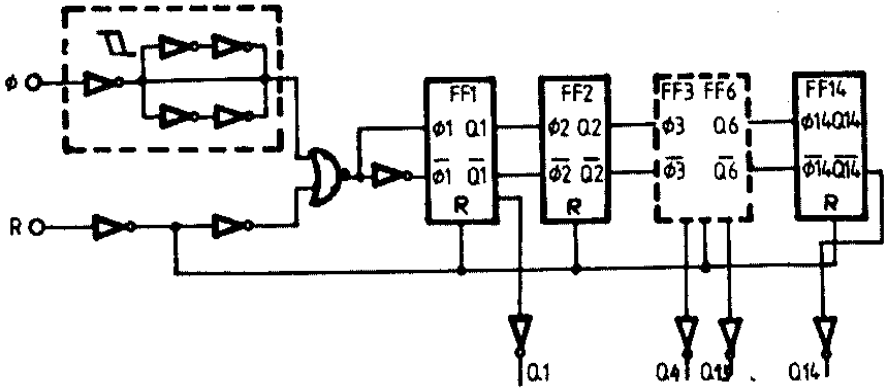


MMC 4040

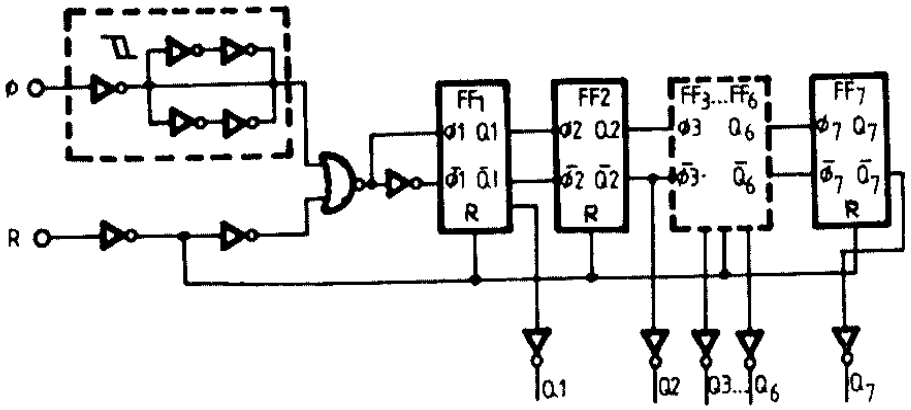


LOGIC DIAGRAM

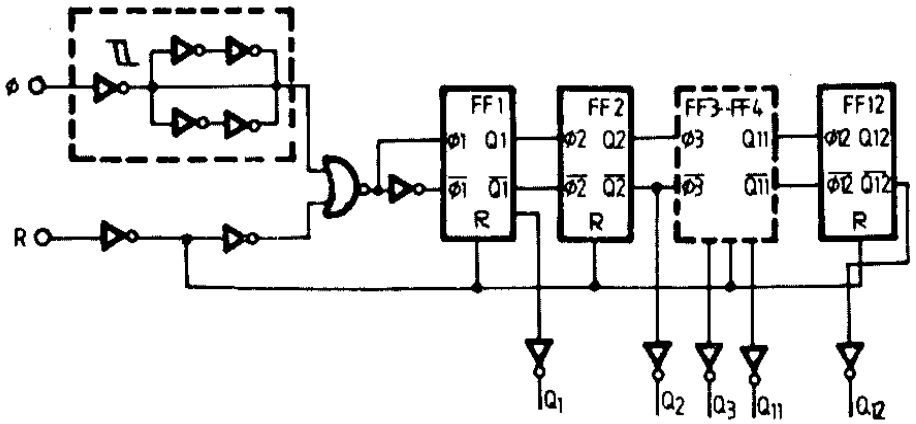
MMC 4020



MMC 4024



MMC 4040



STATIC ELECTRICAL CHARACTERISTICS

(over recommended operating conditions)

PARAMETER			TEST CONDITIONS				VALUES							UNIT
			V_I (V)	V_O (V)	$\|I_O\|$ (μA)	V_{DD} (V)	T^*_{LOW} min.	T^*_{LOW} max.	25°C min.	25°C typ.	25°C max.	T^*_{HIGH} min.	T^*_{HIGH} max.	
I_L	Quiescent current	G, H types	0/ 5			5		5		0.04	5		150	μA
			0/10			10		10		0.04	10		300	
			0/15			15		20		0.04	20		600	
			0/20			20		100		0.08	100		3000	
		E, F types	0/ 5			5		20		0.04	20		150	
			0/10			10		40		0.04	40		300	
			0/15			15		80		0.04	80		600	
V_{OH}	Output high voltage		0/ 5		< 1	5	4.95		4.95			4.95		V
			0/10		< 1	10	9.95		9.95			9.95		
			0/15		< 1	15	14.95		14.95			14.95		
V_{OL}	Output low voltage		5 /0		< 1	5		0.05			0.05		0.05	V
			10/0		< 1	10		0.05			0.05		0.05	
			15/0		< 1	15		0.05			0.05		0.05	
V_{IH}	Input high voltage			0.5/4.5	< 1	5	3.5		3.5			3.5		V
				1/9	< 1	10	7		7			7		
				1.5/13.5	< 1	15	11		11			11		
V_{IL}	Input low voltage			4.5/0.5	< 1	5		1.5			1.5		1.5	V
				9/1	< 1	10		3			3		3	
				13.5/1.5	< 1	15		4			4		4	
I_{OH}	Output drive current	G, H types	0/ 5	2.5		5	−2		−1.6	−3.2		−1.15		mA
			0/ 5	4.6		5	−0.64		−0.51	−1		−0.36		
			0/10	9.5		10	−1.6		−1.3	−2.6		−0.9		
			0/15	13.5		15	−4.2		−3.4	−6.8		−2.4		
		E, F types	0/ 5	2.5		5	−1.53		−1.36	−3.2		−1.1		
			0/ 5	4.6		5	−0.52		−0.44	−1		−0.36		
			0/10	9.5		10	−1.3		−1.1	−2.6		−0.9		
			0/15	13.5		15	−3.6		−3.0	−6.8		−2.4		
I_{OL}	Output sink current	G, H types	0/ 5	0.4		5	0.64		0.51	1		0.36		mA
			0/10	0.5		10	1.6		1.3	2.6		0.9		
			0/15	1.5		15	4.2		3.4	6.8		2.4		
		E, F types	0/ 5	0.4		5	0.52		0.44	1		0.36		
			0/10	0.5		10	1.3		1.1	2.6		0.9		
			0/15	1.5		15	3.6		3.0	6.8		2.4		
I_{IH}, I_{IL}	Input leakage current	G, H types	0/18	Any input		18		±0.1		$±10^{-5}$	±0.1		±1	μA
		E, F types	0/15			15		±0.3		$±10^{-5}$	±0.3		±1	
C_I	Input capacitance			Any input						5	7.5			pF

* T_{LOW} = −55°C for G, H devices; −40°C for E, F devices.

* T_{HIGH} = +125°C for G, H devices; +85°C for E, F devices.

The Noise Margin for both "1" and "0" level is:

1 V min. with V_{DD} = 5 V

2 V min. with V_{DD} = 10 V

2.5 V min. with V_{DD} = 15 V

DYNAMIC ELECTRICAL CHARACTERISTICS

(T_A = 25°C, C_L = 50 pF, R_L = 200 kohm, typical temperature coefficient for all V_{DD} = 0.3%/°C values, all input rise and fall time = 20 ns)

PARAMETER		TEST CONDITIONS V_{DD} (V)	VALUES min.	VALUES typ.	VALUES max.	UNIT
Input pulse operation						
t_{PLH} t_{PHL}	Propagation delay time (Φ to Q1 Out)	5 10 15		180 80 65	360 160 130	ns
t_{PLH} t_{PHL}	Propagation delay time Qn to Qn+1	5 10 15		100 40 30	200 80 60	ns
t_{TLH} t_{THL}	Transition time	5 10 15		100 50 40	200 100 80	ns
t_W	Minimum input pulse width	5 10 15		70 30 20	140 60 40	ns
t_r, t_f	Input rise and fall time	5 10 15	Unlimited			µs
f_{max}	Maximum input clock frequency	5 10 15	3.5 8 12	7 16 24		MHz
Reset operation						
t_{PHL}	Propagation delay time	5 10 15		140 60 50	280 120 100	ns
t_W	Minimum reset pulse width	5 10 15		100 40 30	200 80 60	ns
t_{rem}	Reset removal time	5 10 15		175 75 50	350 150 100	ns

Detail of flip-flop stage